



STPS20L40CF/CW/CT/CFP

LOW DROP POWER SCHOTTKY RECTIFIER

MAJOR PRODUCTS CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	40 V
$T_j(max)$	150°C
$V_F(max)$	0.5 V

FEATURES AND BENEFITS

- LOW FORWARD VOLTAGE DROP MEANING VERY SMALL CONDUCTION LOSSES
- LOW DYNAMIC LOSSES AS A RESULT OF THE SCHOTTKY BARRIER
- INSULATED PACKAGE: ISOWATT220AB, TO-220FPAB
Insulating voltage = 200V DC
Capacitance = 12pF
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

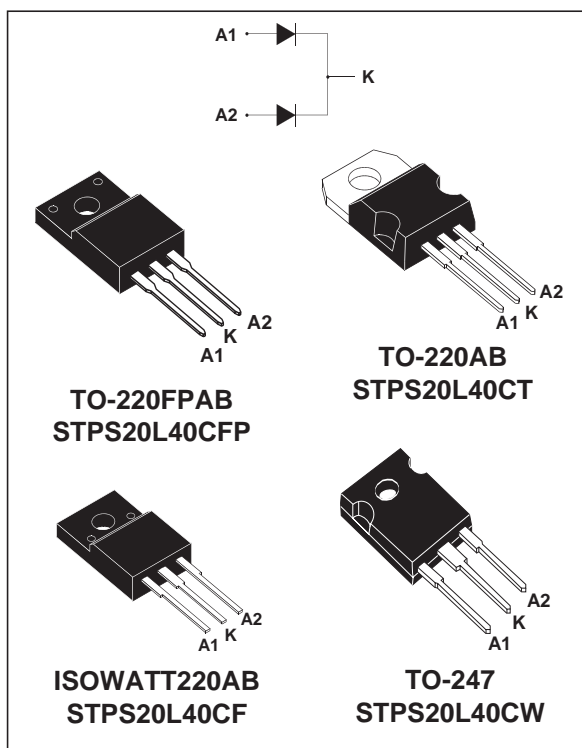
Dual center tap Schottky rectifiers designed for high frequency switched mode power supplies and DC to DC converters.

These devices are intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			40	V	
$I_{F(RMS)}$	RMS forward current			30	A	
$I_{F(AV)}$	Average forward current	TO-220AB	$T_c = 135^\circ\text{C}$ $\delta = 0.5$	Per diode	10	A
		TO-247		Per device	20	
		ISOWATT220AB TO-220FPAB	$T_c = 115^\circ\text{C}$ $\delta = 0.5$	Per diode	10	A
I_{FSM}	Surge non repetitive forward current		$t_p = 10\text{ ms}$ Sinusoidal	180	A	
I_{RRM}	Peak repetitive reverse current		$t_p = 2\ \mu\text{s}$ square $F=1\text{kHz}$	1	A	
I_{RSM}	Non repetitive peak reverse current		$t_p = 100\ \mu\text{s}$ square	2	A	
P_{ARM}	Repetitive peak avalanche power		$t_p = 1\ \mu\text{s}$ $T_j = 25^\circ\text{C}$	4000	W	
T_{stg}	Storage temperature range			- 65 to + 150	°C	
T_j	Maximum operating junction temperature *			150	°C	
dV/dt	Critical rate of rise of reverse voltage			10000	V/ μs	

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink



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THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	ISOWATT220AB TO-220FPAB	Per diode	4.5	$^{\circ}\text{C}/\text{W}$
			Total	3.5	
			Coupling	2.5	
$R_{th(j-c)}$	Junction to case	TO-247	Per diode	2.2	$^{\circ}\text{C}/\text{W}$
			Total	1.20	
			Coupling	0.3	
$R_{th(j-c)}$	Junction to case	TO-220AB	Per diode	2.2	$^{\circ}\text{C}/\text{W}$
			Total	1.3	
			Coupling	0.3	

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
I_R^*	Reverse leakage current	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			0.7	mA
		$T_j = 100^{\circ}\text{C}$			15	35	
V_F^*	Forward voltage drop	$T_j = 25^{\circ}\text{C}$	$I_F = 10 \text{ A}$			0.55	V
		$T_j = 125^{\circ}\text{C}$	$I_F = 10 \text{ A}$		0.44	0.5	
		$T_j = 25^{\circ}\text{C}$	$I_F = 20 \text{ A}$			0.73	
		$T_j = 125^{\circ}\text{C}$	$I_F = 20 \text{ A}$		0.62	0.72	

Pulse test : * $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation :
 $P = 0.28 \times I_{F(AV)} + 0.022 I_{F(RMS)}^2$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

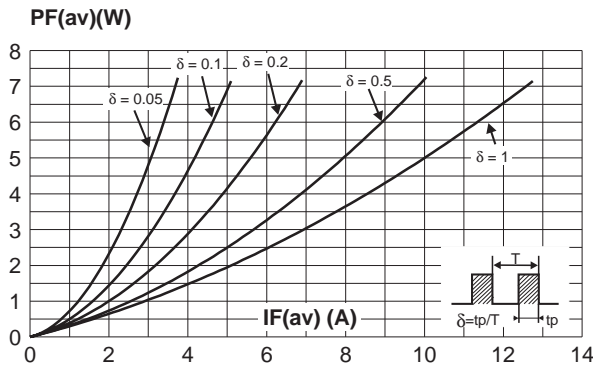


Fig. 2: Average forward current versus ambient temperature ($\delta = 0.5$, per diode).

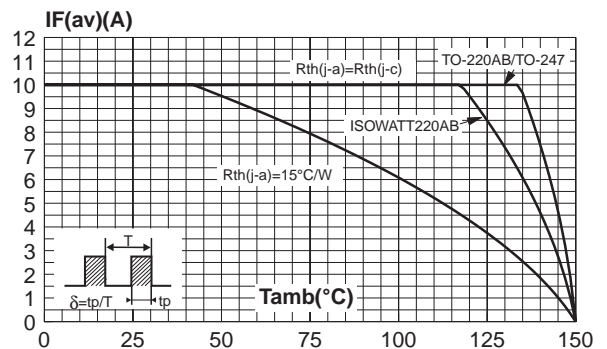


Fig. 3: Normalized avalanche power derating versus pulse duration.

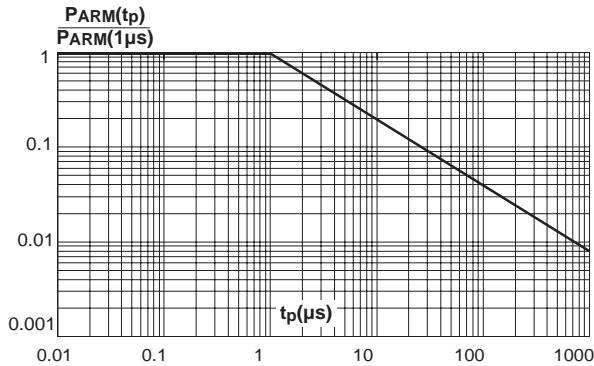


Fig. 4: Normalized avalanche power derating versus junction temperature.

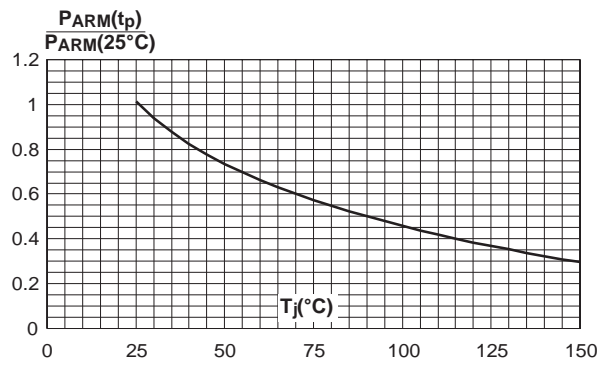


Fig. 5-1: Non repetitive surge peak forward current versus overload duration (maximum values, per diode, TO-220AB / TO-247).

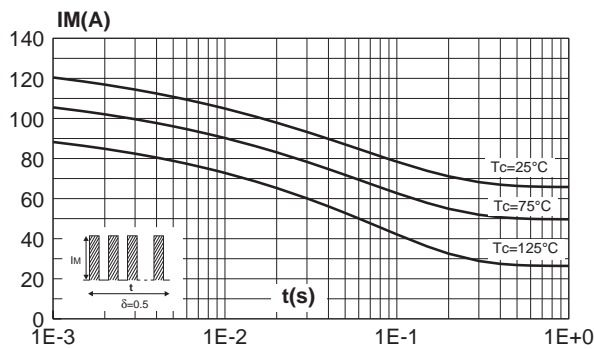


Fig. 5-2: Non repetitive surge peak forward current versus overload duration (maximum values, per diode, ISOWATT220AB, TO-220FPAB).

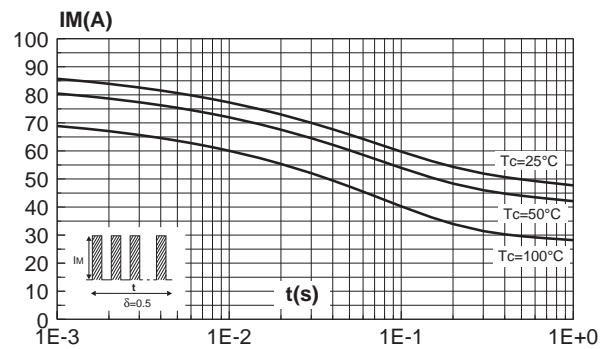


Fig. 6-1: Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB / TO-247).

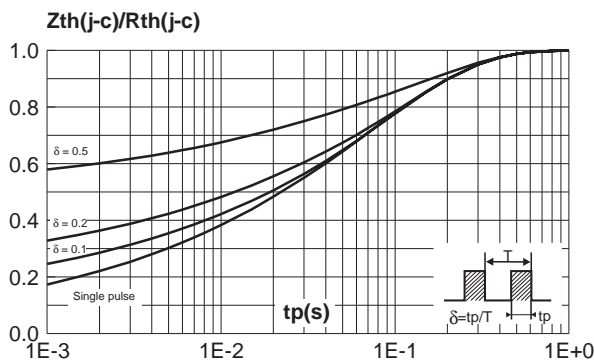


Fig. 6-2: Relative variation of thermal impedance junction to case versus pulse duration (ISOWATT220AB, TO-220FPAB).

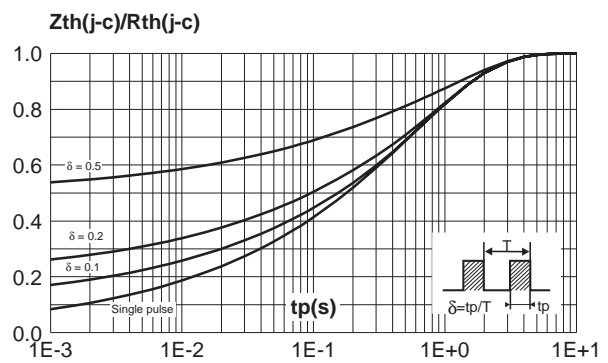


Fig. 7: Reverse leakage current versus reverse voltage applied (typical values, per diode).

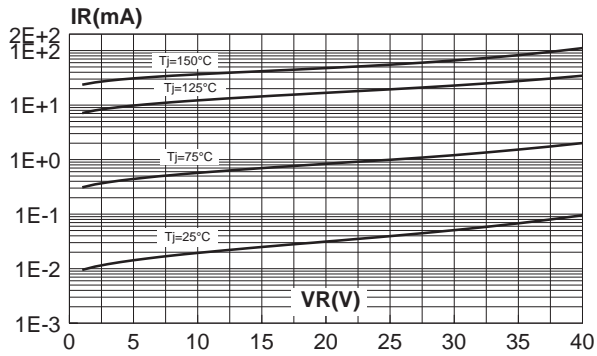


Fig. 8: Junction capacitance versus reverse voltage applied (typical values, per diode).

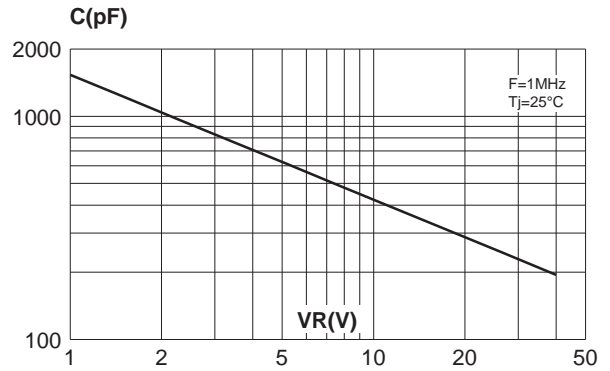
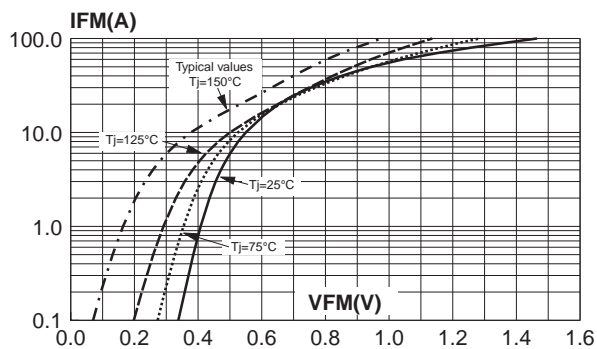
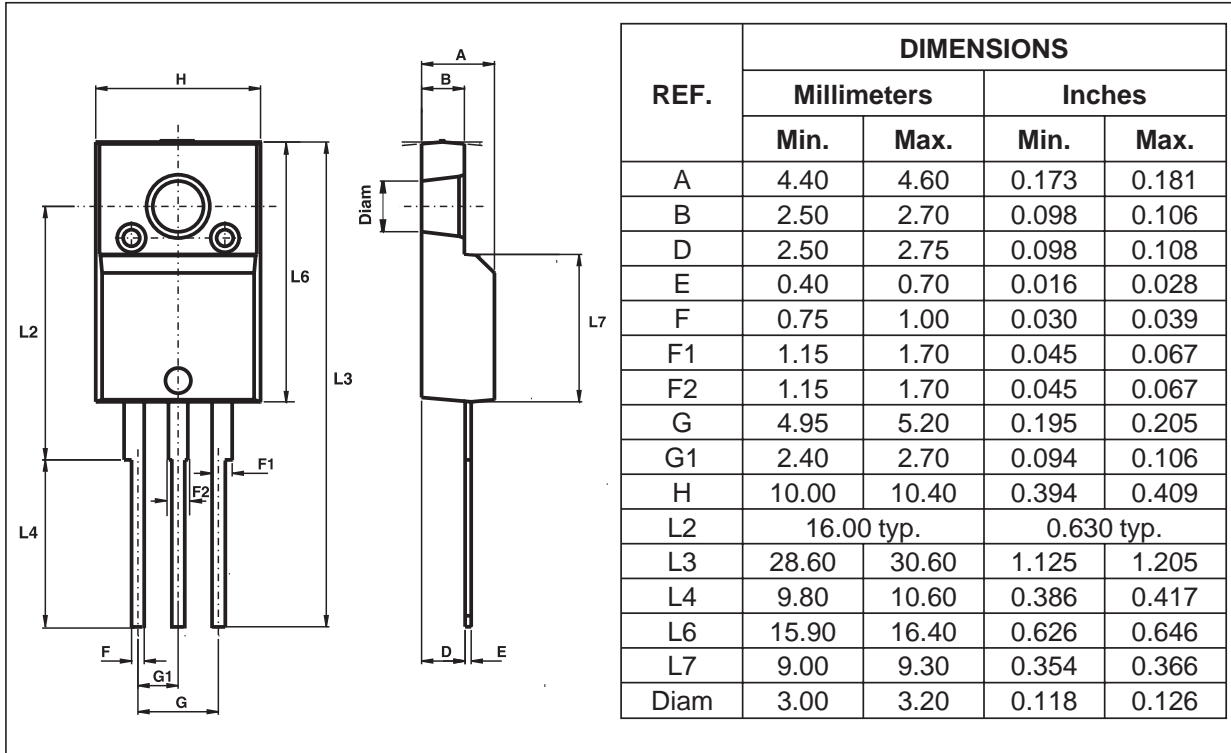


Fig. 9: Forward voltage drop versus forward current (maximum values) (per diode).



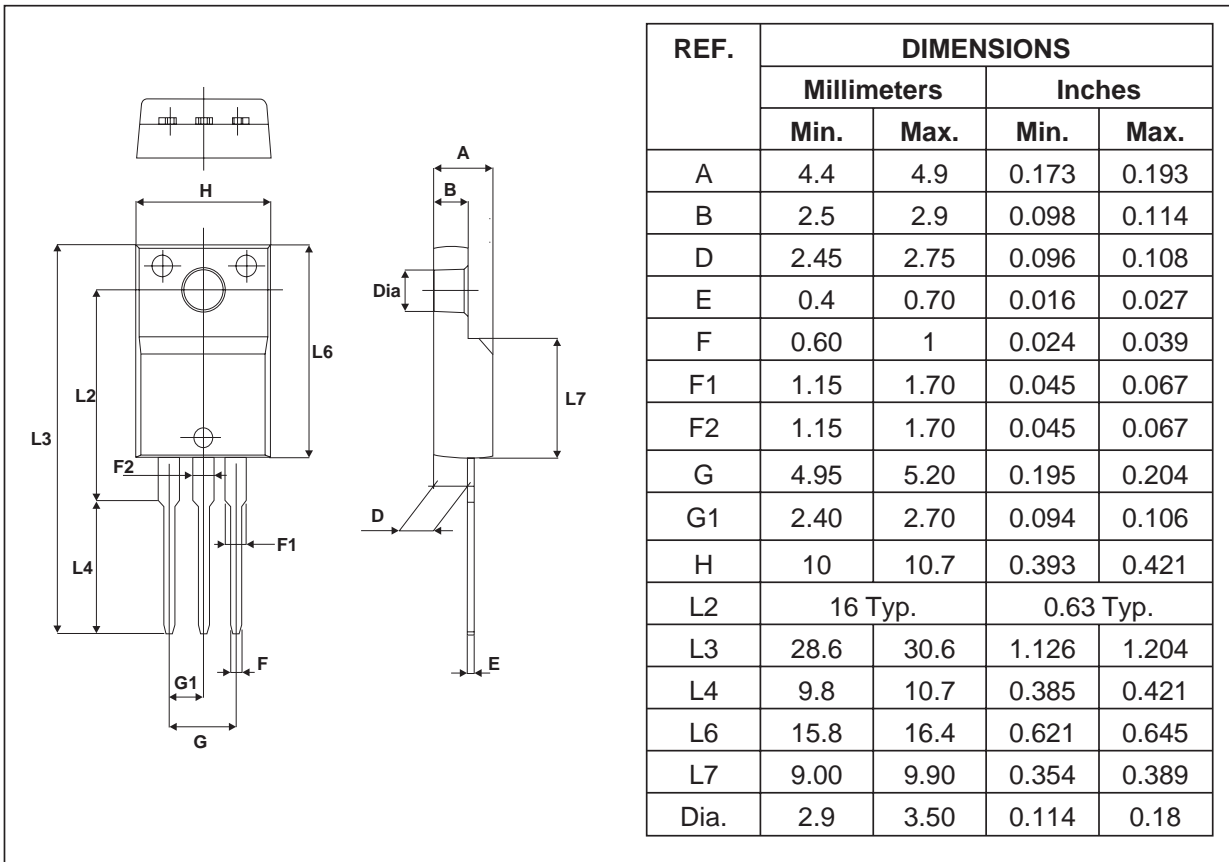
PACKAGE MECHANICAL DATA
ISOWATT220AB



- Cooling method : C
- Recommended torque value : 0.55 m.N
- Maximum torque value : 0.70 m.N

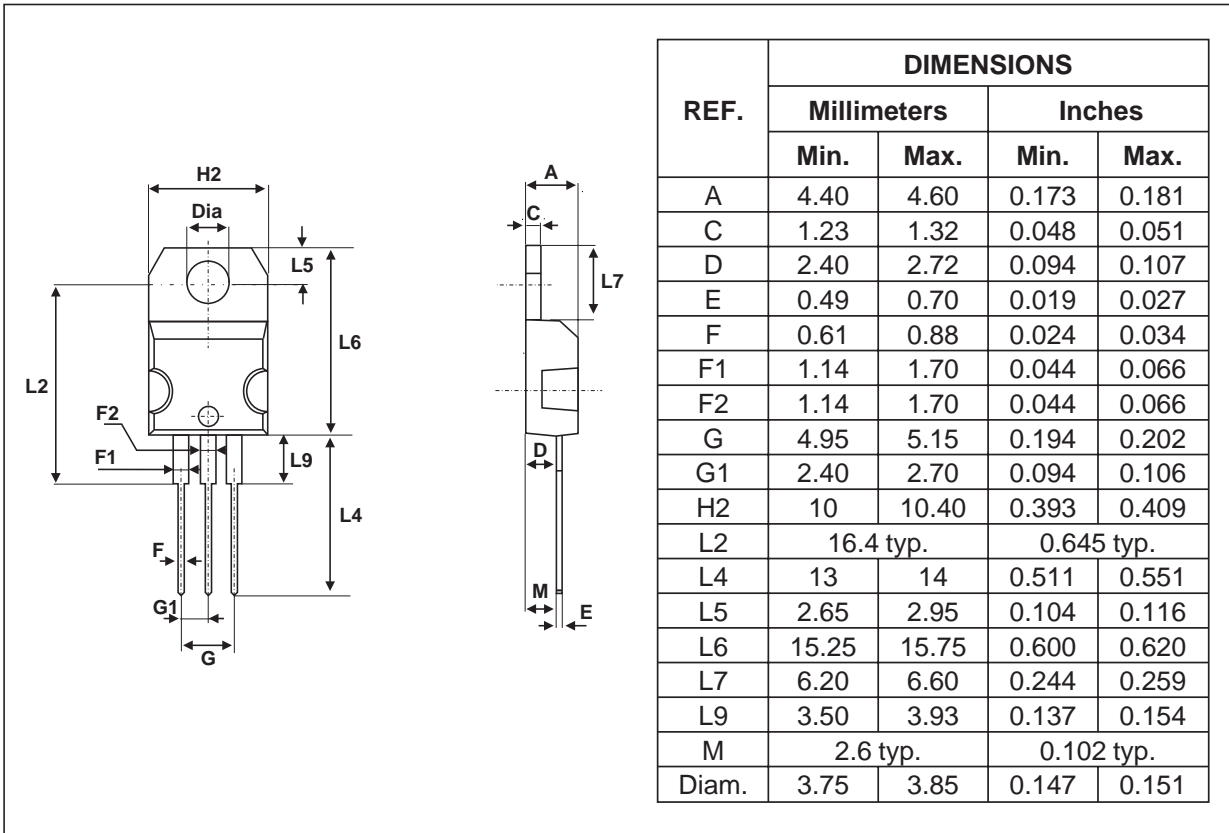
STPS20L40CF/CW/CT/CFP

PACKAGE MECHANICAL DATA
TO-220FPAB



- Cooling method : C
- Recommended torque value : 0.55 m.N
- Maximum torque value : 0.70 m.N

PACKAGE MECHANICAL DATA
TO-220AB

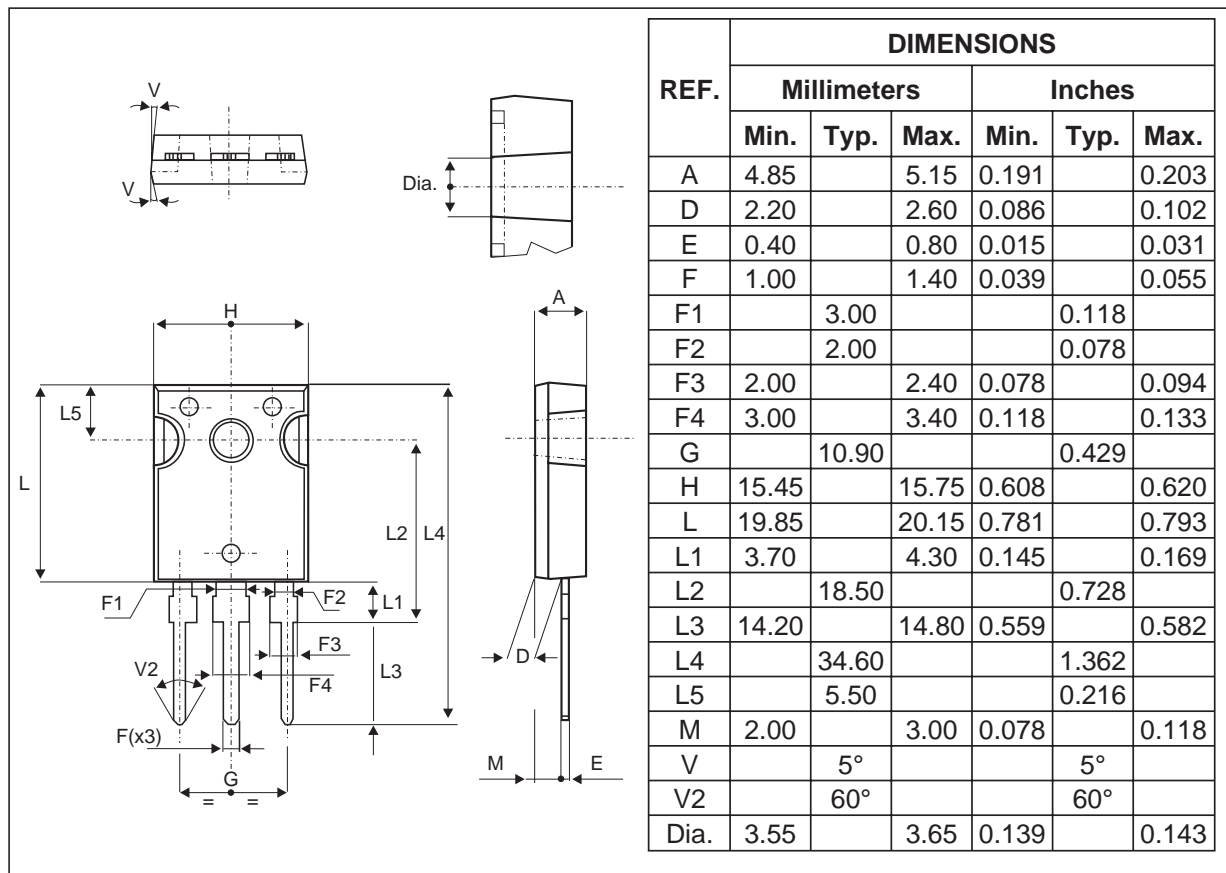


- Cooling method : C
- Recommended torque value : 0.55 m.N
- Maximum torque value : 0.70 m.N

STPS20L40CF/CW/CT/CFP

PACKAGE MECHANICAL DATA

TO-247



- Cooling method : C
- Recommended torque value : 0.8m.N
- Maximum torque value : 1.0m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20L40CF	STPS20L40CF	ISOWATT220AB	2.1g	50	Tube
STPS20L40CFP	STPS20L40CFP	TO-220FPAB	2g	50	Tube
STPS20L40CT	STPS20L40CT	TO-220AB	2g	50	Tube
STPS20L40CW	STPS20L40CW	TO-247	4.4g	30	Tube

- Epoxy meets UL94,V0

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